VS-1N1183, VS-1N3765, VS-1N1183A, VS-1N2128A Series



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Power Silicon Rectifier Diodes, (Stud Version), 35 A, 40 A, 60 A



FEATURES

· Low leakage current series · Good surge current capability up to 1000 A



RoHS

COMPLIANT • Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DO-5 (DO-203AB)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	35 A, 40 A, 60 A				
Package	DO-5 (DO-203AB)				
Circuit configuration	Single				

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS	
		35 ⁽¹⁾	35 ⁽¹⁾	40 ⁽¹⁾	60 ⁽¹⁾	А	
IF(AV)	T _C	140 (1)	140 (1)	150 ⁽¹⁾	140 (1)	°C	
I _{FSM}	50 Hz	480	380	765	860	•	
	60 Hz	500 ⁽¹⁾	400 (1)	800 (1)	900 (1)	A	
l ² t	50 Hz	1140	730	2900	3700	A2-	
	60 Hz	1040	670	2650	3400	A-s	
l²√t		16 100	10 300	41 000	52 500	A²√s	
V _{RRM}	Range	50 to 600 ⁽¹⁾	700 to 1000 ⁽¹⁾	50 to 600 ⁽¹⁾	50 to 600 ⁽¹⁾	V	
TJ		-65 to +200	-65 to +200	-65 to +200	-65 to +200	°C	

Note

(1) JEDEC[®] registered values

ELECTRICAL SPECIFICATIONS

VOLTAGE RA	TINGS			
TYPE NUMBER			V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _J = -65 °C to +200 °C ⁽²⁾) V	V _{RM} , MAXIMUM DIRECT REVERSE VOLTAGE (T _J = -65 °C to +200 °C ⁽²⁾) V
VS-1N1183	VS-1N1183A	VS-1N2128A	50 ⁽¹⁾	50 ⁽¹⁾
VS-1N1184	VS-1N1184A	VS-1N2129A	100 (1)	100 (1)
VS-1N1185	VS-1N1185A	VS-1N2130A	150 ⁽¹⁾	150 ⁽¹⁾
VS-1N1186	VS-1N1186A	VS-1N2131A	200 (1)	200 (1)
VS-1N1187	VS-1N1187A	VS-1N2133A	300 (1)	300 (1)
VS-1N1188	VS-1N1188A	VS-1N2135A	400 (1)	400 (1)
VS-1N1189	VS-1N1189A	VS-1N2137A	500 (1)	500 ⁽¹⁾
VS-1N1190	VS-1N1190A	VS-1N2138A	600 ⁽¹⁾	600 ⁽¹⁾
VS-1N3765	VS-1N2160		700 (1)	700 (1)
VS-1N3766			800 (1)	800 (1)
VS-1N3767			900 (1)	900 (1)
VS-1N3768			1000 (1)	1000 (1)

Notes

Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g., 1N1188R, 1N3766R, 1N1186RA, 1N2135RA

(1) JEDEC[®] registered values

⁽²⁾ For 1N1183 Series and 1N3765 Series $T_C = -65$ °C to +190 °C

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FORWARD CONDUCTION									
PARAMETER		SYMBOL	TEST CONDITIONS		1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum average fo	orward current	1-phase operation,			35 ⁽¹⁾	35 ⁽¹⁾	40 ⁽¹⁾	60 ⁽¹⁾	А
at case temperature		'F(AV)	180° sinusoidal conduction		140 ⁽¹⁾	140 ⁽¹⁾	150 ⁽¹⁾	140 ⁽¹⁾	°C
		-	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V _{RRM} applied	480	380	765	860	- A
Maximum peak one cycle non-repetitive surge current	Half cycle 60 Hz sine wave or 5 ms rectangular pulse		500 ⁽¹⁾		400 ⁽¹⁾	800 ⁽¹⁾	900 (1)		
	IFSM	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with $\frac{1}{2} V_{RRM}$ applied following surge = 0	570	455	910	1000		
				Half cycle 60 Hz sine wave or 5 ms rectangular pulse	595	475	950	1050	
Maximum I ² t for fusing		- I ² t	t = 10 ms	With rated V_{RRM} applied following surge, initial $T_J = T_J$ maximum	1140	730	2900	3700	A26
			t = 8.3 ms		1040	670	2650	3400	
Maximum I ² t for individual device fusing			t = 10 ms	With $V_{RRM} = 0$ following surge, initial $T_J = T_J$ maximum	1610	1030	4150	5250	A-5
			t = 8.3 ms		1470	940	3750	4750	
Maximum I²√t for ind device fusing	dividual	I²√t (2)	t = 0.1 to 10 ms, V _{RRM} = 0 following surge		16 100	10 300	41 500	52 500	A²√s
Maximum peak forward voltage at maximum forward current (I _{FM})		V _{FM}	T _J = 25 °C		1.7 ⁽¹⁾	1.8 ⁽¹⁾	1.3 ⁽¹⁾	1.3 ⁽¹⁾	V
					110	110	126	188	A
Maximum average — reverse current —	$V_{RRM} = 700$		Maximum rated Iron and To		-	5.0 ⁽¹⁾	-	-	
	$V_{RRM} = 800$				-	4.0 ⁽¹⁾	-	-	1
	$V_{RRM} = 900$	I _{R(AV)}	maximan rated IF((v)	-	3.0 ⁽¹⁾	-	-	mA
	V _{RRM} = 1000				-	2.0 (1)	-	-	
			Maximum rated IF(A	$_{\rm AV)}$, $V_{\rm RRM}$ and $T_{\rm C}$	10 ⁽¹⁾	-	2.5 ⁽¹⁾	10 ⁽¹⁾	

Notes

(1) JEDEC[®] registered values

⁽²⁾ I²t for time $t_x = I^2 \sqrt{t} \times \sqrt{t_x}$

THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS	
Maximum operating case temperature range	T _C		-65 to +190 ⁽¹⁾ -6			+200	ŝ	
Maximum storage temperature range	T _{Stg}		-65 to -	+175 ⁽¹⁾	-65 to +200		U	
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	1.00 ⁽¹⁾		1.1 ⁽¹⁾	0.65 ⁽¹⁾	°C 444	
Thermal resistance, case to sink	R _{thCS}	Mounting surface, smooth, flat and greased		C).25	25		
		Not lubricated thread, tighting on nut ⁽²⁾	3.4 (30)					
Maximum allowable mounting torque (+ 0 %, - 10 %)		Lubricated thread, tighting on nut ⁽²⁾	2.3		3 (20)		N⋅m	
		Not lubricated thread, tighting on hexagon ⁽³⁾	4.2 (37)		2 (37)	7)		
		Lubricated thread, tighting on hexagon (3)	3.2 (28)					
Approvimate weight			17			g		
Approximate weight			0.6				oz.	
Case style		JEDEC®	DO-5 (DO-203AB)					

Notes

⁽¹⁾ JEDEC registered values[®]

⁽²⁾ Recommended for pass-through holes

⁽³⁾ Recommended for holed threaded heatsinks

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2

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Fig. 1 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N1183 and 1N3765 Series











I_F - Instantaneous Forward Voltage (V)

Fig. 4 - Typical Forward Voltage vs. Forward Current, 1N1183 and 1N3765 Series



Fig. 5 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183 and 1N3765 Series





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3

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Fig. 7 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N1183A Series



Average Forward Current Over Full Cycle (A) Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N1183A Series





Average Forward Current, 1N2128A Series

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4

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T₁ = 25 °C

3

Instantaneous Forward Voltage (V) Fig. 15 - Maximum Forward Voltage vs. Forward Current, 1N2128A Series

4

5

6

7

2

1

10¹

1.0 0



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DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)







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